Vishay General Semiconductor



High Current Density Surface Mount Ultrafast Rectifiers



DO-220AA (SMP)

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

t_{rr}

 V_F at $I_F = 2 A$

T_{.1} max.

FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Glass passivated chip junction
- Ultrafast recovery times for high frequency
- Low forward voltage drop, low power loss
 COMPLIANT
- · Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of ac-to-ac and dc-to-dc converters in high temperature conditions for both consumer and automotive applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
Device marking code		P2B	P2C	P2D		
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.0			А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175			°C	

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

2 A

100 V, 150 V, 200 V

25 ns

0.75 V

175 °C

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 2 A	T _J = 25 °C T _J = 125 °C	V _F	0.90 0.75	0.98 0.82	V
Maximum reverse current (1)	rated V _R	T _J = 25 °C T _J = 125 °C	I _R	0.2 12.6	1.0 25	μΑ





New Product ESH2PB, ESH2PC & ESH2PD

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	-	25	ns	
Typical reverse recovery time	I _F = 1.0 A, V _R = 30 V, dI/dt = 50 A/μs,	T _J = 25 °C T _J = 100 °C	t _{rr}	-	25 35	ns	
Typical stored charge	$I_{rr} = 10 \% I_{RM}$		Q _{rr}	-	10 15	nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	-	25	pF	

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
Typical thermal resistance ⁽¹⁾	$f R_{ heta JA} \ f R_{ heta JL} \ f R_{ heta JL} \ f R_{ heta JC}$	80 15 22		°C/W		

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
ESH2PB-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
ESH2PB-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel			
ESH2PBHE3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel			
ESH2PBHE3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel			

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

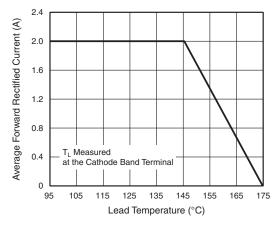


Figure 1. Forward Current Derating Curve

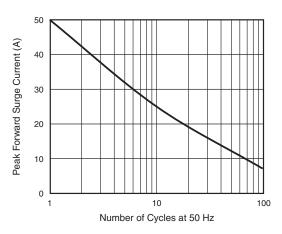


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

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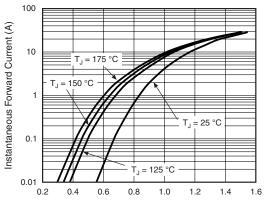
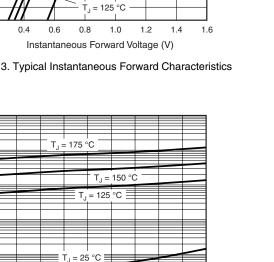


Figure 3. Typical Instantaneous Forward Characteristics

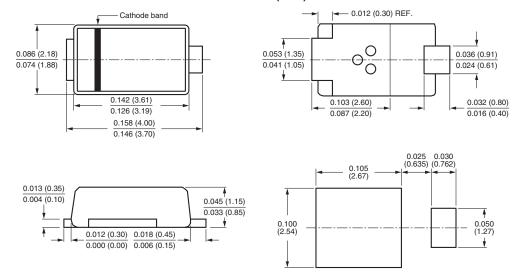


20 30 40 70 100 10 50 60 80 90 Percent of Rated Peak Reverse Voltage (%)

Figure 4. Typical Reverse Leakage Characteristics



DO-220AA (SMP)



1000

100

10

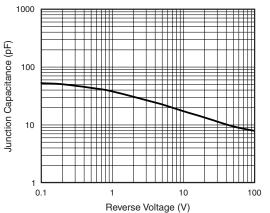
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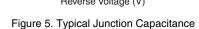
0.1

0.01

Instantaneous Reverse Current (µA)

For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com Document Number: 89016 Revision: 18-Apr-08









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